

150mA, 75V Switching Diode

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliance to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

• Case: SOD-123F

- Molding compound meets UL 94 V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- · Polarity: Indicated by cathode band
- Weight: 8.85 ± 0.5mg

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
l _F	150	mA	
V_{RRM}	75	V	
I _{FSM}	2	Α	
V _F at I _F =100mA	1.00	٧	
T _J Max.	150	°C	
Package	SOD-123F		
Configuration	Single die		







ABSOLUTE MAXIMUM	RATINGS (T _A = 25°C un	less otherwise noted)		
PARAMETER		SYMBOL	VALUE	UNIT
	1N4148W		D1	
Marking code on the device	1N4448W		D2	
	1N914BW		D3	
Power dissipation		P _D	400	mW
Reverse voltage		V_R	100	V
Repetitive peak reverse voltage		V_{RRM}	75	V
Forward current		I _F	150	mA
Repetitive peak forward current		I _{FRM}	300	mA
Non-repetitive peak forward surge current @ t=1.0µs		I _{FSM}	2	Α
Junction temperature range		TJ	-65 to +150	°C
Storage temperature range		T _{STG}	-65 to +150	°C

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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	450	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	MIN	MAX	UNIT
Forward voltage (1)	1N4448W, 1N914BW	$I_F = 5 \text{mA}, T_J = 25 ^{\circ}\text{C}$		0.62	0.72	V
	1N4148W	I _F = 10mA, T _J = 25°C	V_{F}	-	1.00	
voitage	1N4448W, 1N914BW	I _F = 100mA, T _J = 25°C]	-	1.00	
Reverse voltage		I _R =100μA, T _J = 25°C	V_R	100	-	V
		I _R =5μA, T _J = 25°C		75	-	
Reverse leakage current (2)		V _R =20V T _J = 25°C		-	25	nA
		V _R =75V T _J = 25°C	I _R	-	5	μA
Junction capacitance		1 MHz, V _R =0V	CJ	-	4	pF
Reverse recovery time		I_F =10mA, I_R =60mA, R_L =100 Ω , I_{RR} =1mA	t _{rr}	-	4	ns

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION			
PART NO.	PACKAGE	PACKING	
1N4148W RHG	SOD-123F	3K / 7" Reel	
1N4148W RH	SOD-123F	3K / 7" Reel	
1N4448W RHG	SOD-123F	3K / 7" Reel	
1N4448W RH	SOD-123F	3K / 7" Reel	
1N914BW RHG	SOD-123F	3K / 7" Reel	
1N914BW RH	SOD-123F	3K / 7" Reel	



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Typical Forward Characteristics

100

100

100

100

0.01

0.001

0.02

0.4

0.6

0.8

1 1.2

1.4

1.6

Instantaneous Forward Voltage (V)

Fig. 2 Reverse Current VS. Reverse Voltage

100

10

10

0.01

0 20 40 60 80 100 120

Reverse Voltage (V)

Fig.3 Admissible Power Dissipation Curve

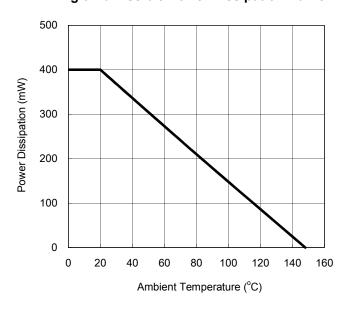
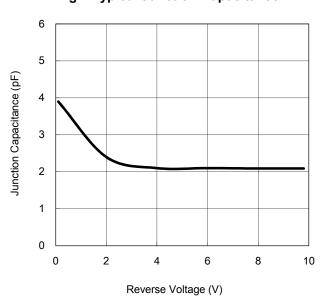


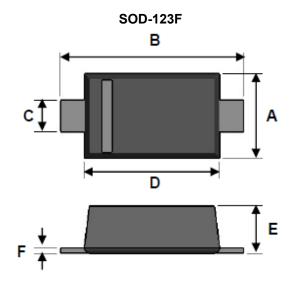
Fig.4 Typical Junction Capacitance





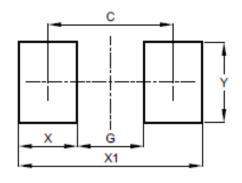
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PACKAGE OUTLINE DIMENSION



D.134	Unit (mm)		Unit (inch)		
DIM.	Min	Max	Min	Max	
А	1.50	1.70	0.059	0.067	
В	3.30	3.90	0.130	0.154	
С	0.50	0.70	0.020	0.028	
D	2.50	2.70	0.098	0.106	
Е	0.80	1.15	0.031	0.045	
F	0.05	0.20	0.002	0.008	

SUGGEST PAD LAYOUT



DIM.	Unit (mm)	Unit (inch) Typ.	
DIW.	Тур.		
С	2.86	0.113	
G	1.52	0.060	
Х	1.34	0.053	
X1	4.20	0.165	
Y	1.80	0.071	



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